NSN 5961-01-374-7826



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Transistor - Page 1 of 1 **Inclosure Material:** Plastic **Overall Length:** Between 2.80 millimeters and 3.04 millimeters **Overall Height:** Between 0.89 millimeters and 1.11 millimeters **Overall Width:** Between 2.10 millimeters and 2.50 millimeters **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-236ab **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -40.0 breakdown voltage, collector-to-emitter, base open and -40.0 breakdown voltage, collector-to-base, emitter open and -5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** -200.00 milliamperes all primaries **Power Rating Per Characteristic:** 300.0 milliwatts any acceptable preset Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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